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LM193/LM293/LM393/LM2903 Low Power Low Offset Voltage Dual Comparators General Description Advantages

The LM193 series consists of two independent precision voltage comparators with an offset voltage specification as low as 2.0 mV max for two comparators which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

Application areas include limit comparators, simple analog to digital converters; pulse, squarewave and time delay generators; wide range VCO; MOS clock timers; multivibrators and high voltage digital logic gates. The LM193 series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the LM193 series will directly interface with MOS logic where their low power drain is a distinct advantage over standard comparators.

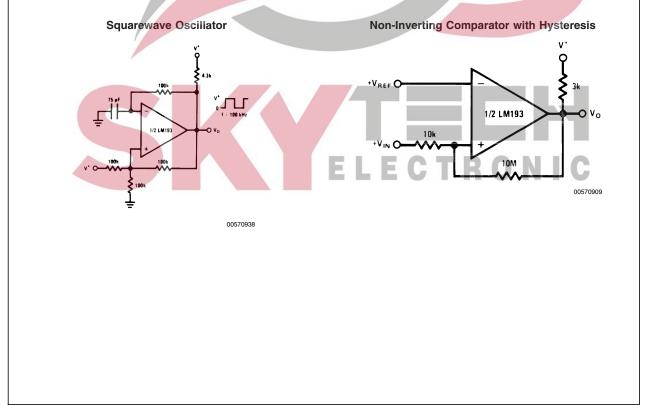
The LM393 and LM2903 parts are available in National's innovative thin micro SMD package with 8 (12 mil) large bumps.

- High precision comparators
- Reduced V_{OS} drift over temperature
- Eliminates need for dual supplies
- Allows sensing near ground
- Compatible with all forms of logic
- Power drain suitable for battery operation

Features

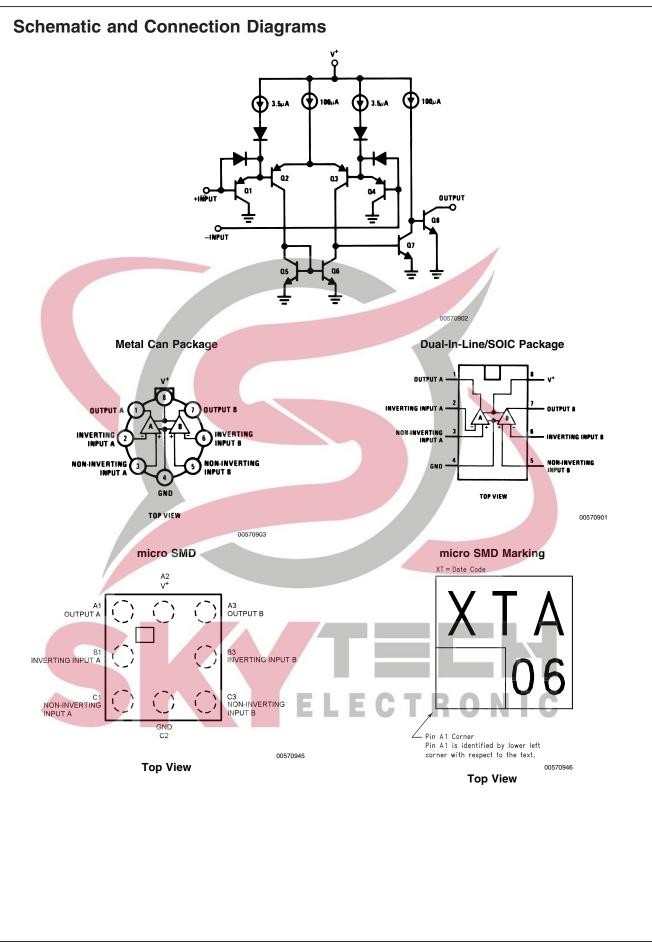
Wide supply	
— Voltage range:	2.0V to 36V
 — Single or dual supplies: 	±1.0V to ±18V
Very low supply current drain (0.4 mA)	 independent
of supply voltage	
Low input biasing current:	25 nA
Low input offset current:	±5 nA
Maximum offset voltage:	±3 mV
Input common-mode voltage range inc	ludes ground
Differential input voltage range equal to	the power
supply voltage	
Low output saturation voltage,:	250 mV at 4 mA

- Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems
- Available in the 8-Bump (12 mil) micro SMD package
- See AN-1112 for micro SMD considerations





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Absolute Maximum Ratings (Note 10)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Distributors for	availability and spe	cincations.	Lead Temperature	
Supply Voltage,	V ⁺	36V	(Soldering, 10 seconds)	+260°C
Differential Input	Voltage (Note 8)	36V	Soldering Information	
Input Voltage		-0.3V to +36V	Dual-In-Line Package	
Input Current (V	_N <-0.3V) (Note 3)	50 mA	Soldering (10 seconds)	260°C
Power Dissipatio	on (Note 1)		Small Outline Package	215°C
Molded DIP		780 mW	Vapor Phase (60 seconds)	
Metal Can		660 mW	Infrared (15 seconds)	220°C
Small Outline	Package	510 mW	See AN-450 "Surface Mounting Methods a	and Their Effect
micro SMD Pa	acakge	568mW	on Product Reliability" for other methods of	of soldering
Output Short-Cire	cuit to Ground		surface mount devices.	
(Note 2)		Continuous	ESD rating	
Operating Tempe	erature Range		(1.5 k Ω in series with 100 pF)	1300V
LM393		0°C to +70°C		
LM293		-25°C to +85°C		

LM193/LM193A

Storage Temperature Range

LM2903

Electrical Characteristics

(V⁺=5V, $T_A = 25^{\circ}C$, unless otherwise stated)

Parameter	Conditions		LM193	4	Units
		Min	Тур	Max	1
Input Offset Voltage	(Note 9)		1.0	2.0	mV
Input Bias Current	I _{IN} (+) or I _{IN} (-) with Output In Linear		25	100	nA
	Range, V _{CM} = 0V (Note 5)				
Input Offset Current	$I_{IN}(+) - I_{IN}(-) V_{CM} = 0V$		3.0	25	nA
Input Common Mode	V+ = 30V (Note 6)	0		V+-1.5	V
Voltage Range					
Supply Current	R _L =∞ V ⁺ =5V		0.4	1	mA
	V+=36V		1	2.5	mA
Voltage Gain	R _L ≥15 kΩ, V ⁺ =15V	50	200		V/mV
/	$V_{O} = 1V$ to 11V				
Large Signal Response	V _{IN} =TTL Logic Swing, V _{REF} =1.4V		300		ns
Time	V_{RL} =5V, R_{L} =5.1 k Ω				
Response Time	V _{RL} =5V, R _L =5.1 kΩ (Note 7)		1.3		μs
Output Sink Current	V _{IN} (-)=1V, V _{IN} (+)=0, V _O ≈1.5V	6.0	16		mA
Saturation Voltage	V _{IN} (-)=1V, V _{IN} (+)=0, I _{SINK} ≤4 mA		250	400	mV
Output Leakage Current	V _{IN} (-)=0, V _{IN} (+)=1V, V _O =5V	CT	0.1		nA nA

Electrical Characteristics

(V⁺=5V, $T_A = 25^{\circ}$ C, unless otherwise stated)

Parameter	Conditions		LM1	93	LM2	293, I	LM393		LM29	03	Units
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Input Offset Voltage	(Note 9)		1.0	5.0		1.0	5.0		2.0	7.0	mV
Input Bias Current	$I_{IN}(+)$ or $I_{IN}(-)$ with Output In		25	100		25	250		25	250	nA
	Linear Range, $V_{CM} = 0V$ (Note 5)										
Input Offset Current	$I_{IN}(+) - I_{IN}(-) V_{CM} = 0V$		3.0	25		5.0	50		5.0	50	nA
Input Common Mode	V+ = 30V (Note 6)	0		V+-1.5	0		V+-1.5	0		V+-1.5	V
Voltage Range											

-55°C to +125°C

–40°C to +85°C

-65°C to +150°C

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Electrical Characteristics (Continued)

(V⁺=5V, $T_A = 25^{\circ}C$, unless otherwise stated)

Parameter		Conditions		LM19	93	LM	293, L	.M393		LM29	03	Units
			Min	Тур	Мах	Min	Тур	Max	Min	Тур	Мах]
Supply Current	R _L =∞	V+=5V		0.4	1		0.4	1		0.4	1.0	mA
		V ⁺ =36V		1	2.5		1	2.5		1	2.5	mA
Voltage Gain	$R_L \ge 15 k\Omega$,	V ⁺ =15V	50	200		50	200		25	100		V/mV
	$V_{\rm O} = 1V$ to	11V										
Large Signal Response	V _{IN} =TTL L	ogic Swing, V _{REF} =1.4V		300			300			300		ns
Time	V _{RL} =5V, R	_L =5.1 kΩ										
Response Time	V _{RL} =5V, R	_=5.1 kΩ (Note 7)		1.3			1.3			1.5		μs
Output Sink Current	$V_{IN}(-)=1V,$	V _{IN} (+)=0, V _O ≤1.5V	6.0	16		6.0	16		6.0	16		mA
Saturation Voltage	$V_{IN}(-)=1V,$	V _{IN} (+)=0, I _{SINK} ≤4 mA		250	400		250	400		250	400	mV
Output Leakage Current	V _{IN} (−)=0, \	/ _{IN} (+)=1V, V _O =5V		0.1			0.1			0.1		nA

Electrical Characteristics

(V+ = 5V) (Note 4)

Parameter	Conditions		LM193A		
		Min	Тур	Max	
Input O <mark>ffset Volt</mark> age	(Note 9)			4.0	mV
Input Offset Current	I _{IN(+)} -I _{IN(-)} , V _{CM} =0V			100	nA
Input Bias Current	I _{IN} (+) or I _{IN} (-) with Output in Linear Range,			300	nA
	V _{CM} =0V (Note 5)				
Input Common Mode	V ⁺ =30V (Note 6)	0		V ⁺ -2.0	V
Voltage Range					
Saturation Voltage	V _{IN} (–)=1V, V _{IN} (+)=0, I _{SINK} ≤4 mA			700	mV
Output Leakage Current	$V_{IN}(-)=0, V_{IN(+)}=1V, V_{O}=30V$			1.0	μA
Differential Input Voltage	Keep All V _{IN} 's≥0V (or V ⁻ , if Used), (Note 8)			36	V

Electrical Characteristics

(v + - 5v) (Note 4)											
Parameter	Conditions		LM19	3	LM	293,	LM393		LM29	903	Units
		Min	Тур	Max	Min	Тур	Мах	Min	Тур	Max	
Input Offset Voltage	(Note 9)			9			9		9	15	mV
Input Offset Current	I _{IN(+)} -I _{IN(-)} , V _{CM} =0V		_	100			150		50	200	nA
Input Bias Current	$I_{IN}(+)$ or $I_{IN}(-)$ with Output in			300			400		200	500	nA
	Linear Range, V _{CM} =0V										
	(Note 5)	8							_		
Input Common Mode	V ⁺ =30V (Note 6)	0		V ⁺ -2.0	0	D	V+-2.0	0	0	V ⁺ -2.0	V
Voltage Range											
Saturation Voltage	$V_{IN}(-)=1V, V_{IN}(+)=0,$			700			700		400	700	mV
	I _{SINK} ≤4 mA										
Output Leakage Current	V _{IN} (-)=0, V _{IN(+)} =1V, V _O =30V			1.0			1.0			1.0	μA
Differential Input Voltage	Keep All V _{IN} 's≥0V (or V [−] , if			36			36			36	V
	Used), (Note 8)										

Note 1: For operating at high temperatures, the LM393 and LM2903 must be derated based on a 125°C maximum junction temperature and a thermal resistance of 170°C/W which applies for the device soldered in a printed circuit board, operating in a still air ambient. The LM193/LM193A/LM293 must be derated based on a 150°C maximum junction temperature. The low bias dissipation and the "ON-OFF" characteristic of the outputs keeps the chip dissipation very small ($P_D \le 100 \text{ mW}$), provided the output transistors are allowed to saturate.

Note 2: Short circuits from the output to V⁺ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 20 mA independent of the magnitude of V⁺.

Note 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action

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Electrical Characteristics (Continued)

on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V^+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3V.

Note 4: These specifications are limited to $-55^{\circ}C \le T_A \le +125^{\circ}C$, for the LM193/LM193A. With the LM293 all temperature specifications are limited to $-25^{\circ}C \le T_A \le +85^{\circ}C$ and the LM393 temperature specifications are limited to $0^{\circ}C \le T_A \le +70^{\circ}C$. The LM2903 is limited to $-40^{\circ}C \le T_A \le +85^{\circ}C$.

Note 5: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.

Note 6: The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V^+ -1.5V at 25°C, but either or both inputs can go to 36V without damage, independent of the magnitude of V^+ .

Note 7: The response time specified is for a 100 mV input step with 5 mV overdrive. For larger overdrive signals 300 ns can be obtained, see typical performance characteristics section.

Note 8: Positive excursions of input voltage may exceed the power supply level. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than -0.3V (or 0.3V below the magnitude of the negative power supply, if used).

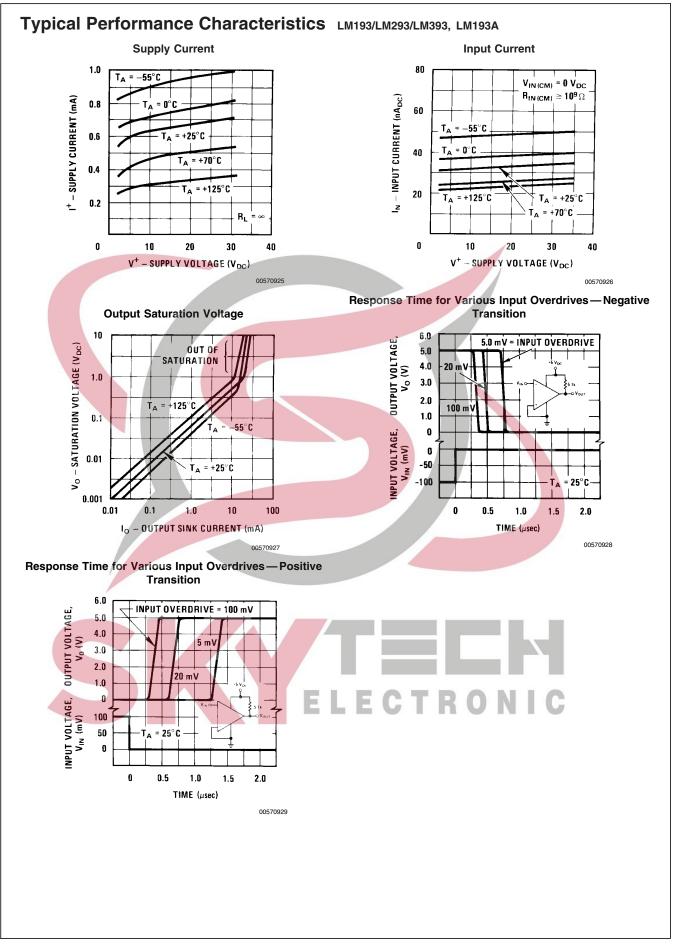
Note 9: At output switch point, $V_0 \approx 1.4V$, $R_S = 0\Omega$ with V⁺ from 5V to 30V; and over the full input common-mode range (0V to V⁺-1.5V), at 25°C. **Note 10:** Refer to RETS193AX for LM193AH military specifications and to RETS193X for LM193H military specifications.

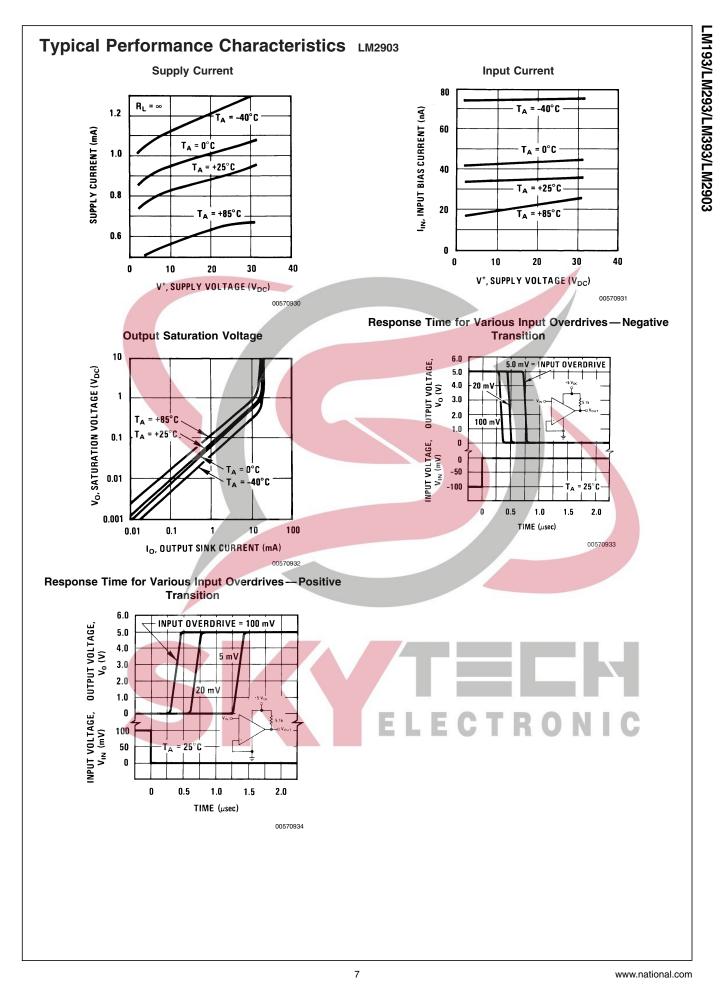
Ordering Information

Package	Temperature Range	Part Number	NSC Drawing			
		LM193H*				
		LM193H/883				
		LM193H-MLS				
	–55°C to 125°C	LM193AH-MLS	1			
8-Pin Metal Can		LM193AH-QMLV**	H08C			
		LM193AH				
		LM193AH/883				
	-25°C to 85°C	LM293H				
	0°C to 70°C	LM393H				
		LM193J/883*				
		LM193AJ/883	1004			
Pin Ceramic DIP	–55°C to 125°C	LM193AJ-QMLV**	J08A			
		LM193AJ-MLS				
D Din Maldad DID	0°C to 70°C LM393N		NOOF			
3-Pin Molded DIP	-40°C to 85°C	LM2903N	N08E			
	0°C to 70°C	LM393M				
	0°C to 70°C -40°C to 85°C -	LM393MX	14004			
8-Pin SOIC		LM2903M	M08A			
	-40 C to 85 C	LM2903MX	1			
	0°C to 70°C	LM393TL				
8-Bump (12 mils)		LM393TLX	TLA08AAA			
micro SMD	-40°C to 85°C	LM2903ITL	ILAUOAAA			
	-40 C to 85 C	LM2903ITLX				
ote: * Also available per Ll ote: ** See STD Mil DWG		ELECT	RONIC			

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Application Hints

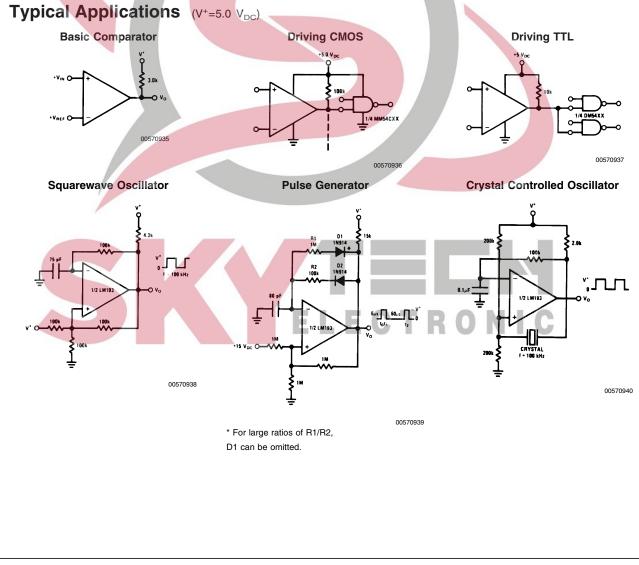
The LM193 series are high gain, wide bandwidth devices which, like most comparators, can easily oscillate if the output lead is inadvertently allowed to capacitively couple to the inputs via stray capacitance. This shows up only during the output voltage transition intervals as the comparator change states. Power supply bypassing is not required to solve this problem. Standard PC board layout is helpful as it reduces stray input-output coupling. Reducing the input resistors to < 10 k Ω reduces the feedback signal levels and finally, adding even a small amount (1.0 to 10 mV) of positive feedback (hysteresis) causes such a rapid transition that oscillations due to stray feedback are not possible. Simply socketing the IC and attaching resistors to the pins will cause input-output oscillations during the small transition intervals unless hysteresis is used. If the input signal is a pulse waveform, with relatively fast rise and fall times, hysteresis is not required.

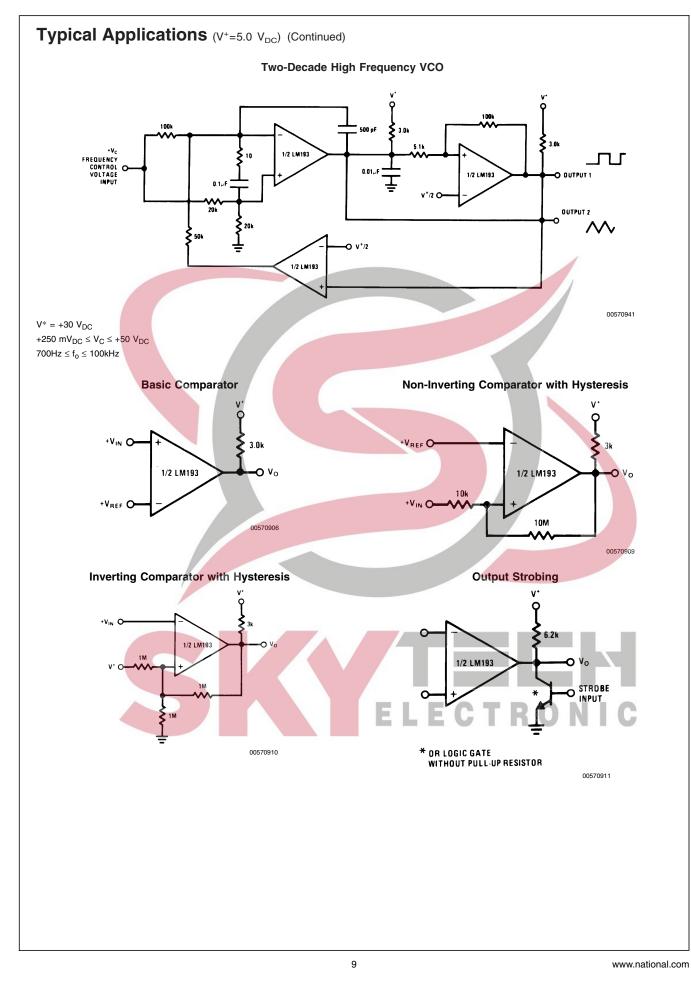
All input pins of any unused comparators should be tied to the negative supply.

The bias network of the LM193 series establishes a drain current which is independent of the magnitude of the power supply voltage over the range of from 2.0 V_{DC} to 30 V_{DC} . It is usually unnecessary to use a bypass capacitor across the power supply line.

The differential input voltage may be larger than V⁺ without damaging the device (Note 8). Protection should be provided to prevent the input voltages from going negative more than $-0.3 V_{\rm DC}$ (at 25°C). An input clamp diode can be used as shown in the applications section.

The output of the LM193 series is the uncommitted collector of a grounded-emitter NPN output transistor. Many collectors can be tied together to provide an output OR'ing function. An output pull-up resistor can be connected to any available power supply voltage within the permitted supply voltage range and there is no restriction on this voltage due to the magnitude of the voltage which is applied to the V⁺ terminal of the LM193 package. The output can also be used as a simple SPST switch to ground (when a pull-up resistor is not used). The amount of current which the output device can sink is limited by the drive available (which is independent of V⁺) and the β of this device. When the maximum current limit is reached (approximately 16mA), the output transistor will come out of saturation and the output voltage will rise very rapidly. The output saturation voltage is limited by the approximately 60Ω r_{SAT} of the output transistor. The low offset voltage of the output transistor (1.0mV) allows the output to clamp essentially to ground level for small load currents.

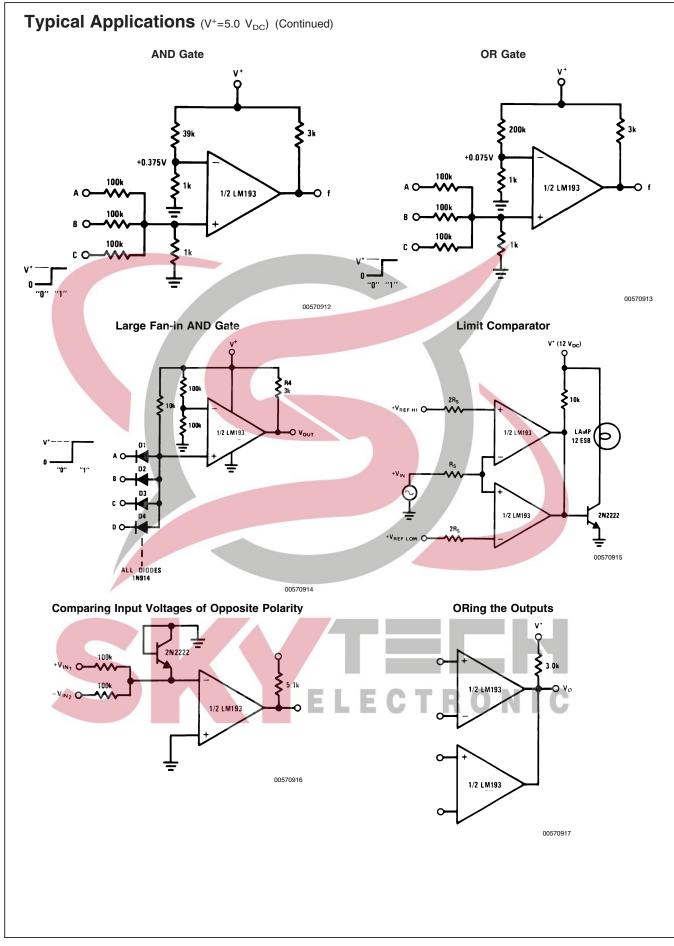


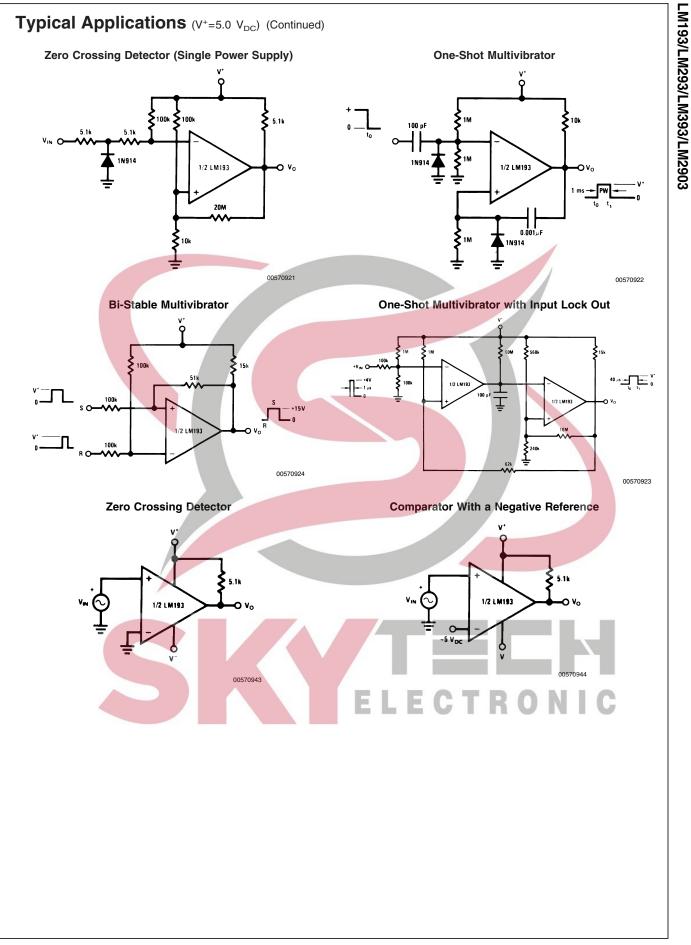


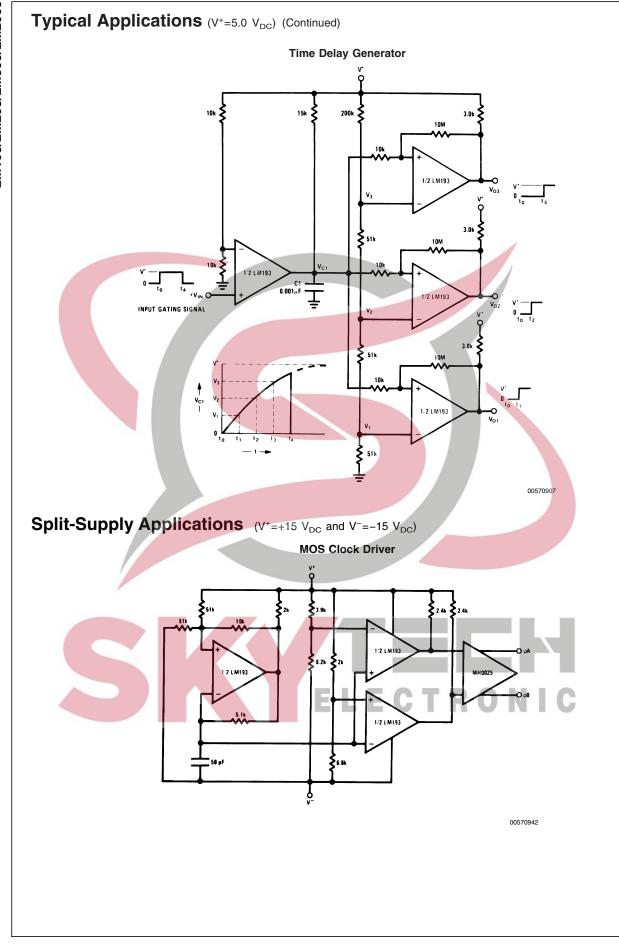
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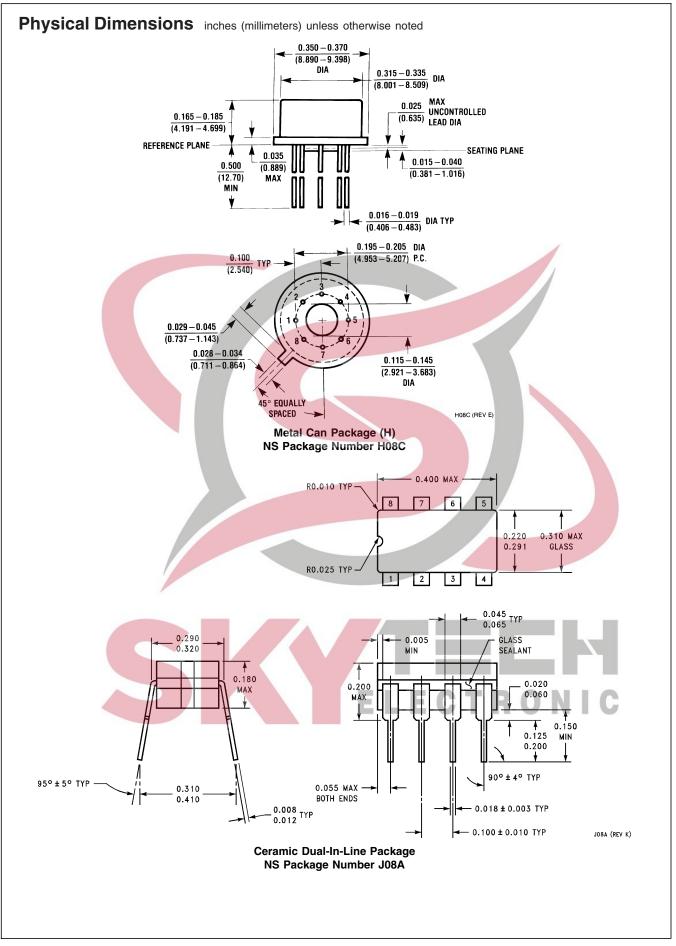
LM193/LM293/LM393/LM2903



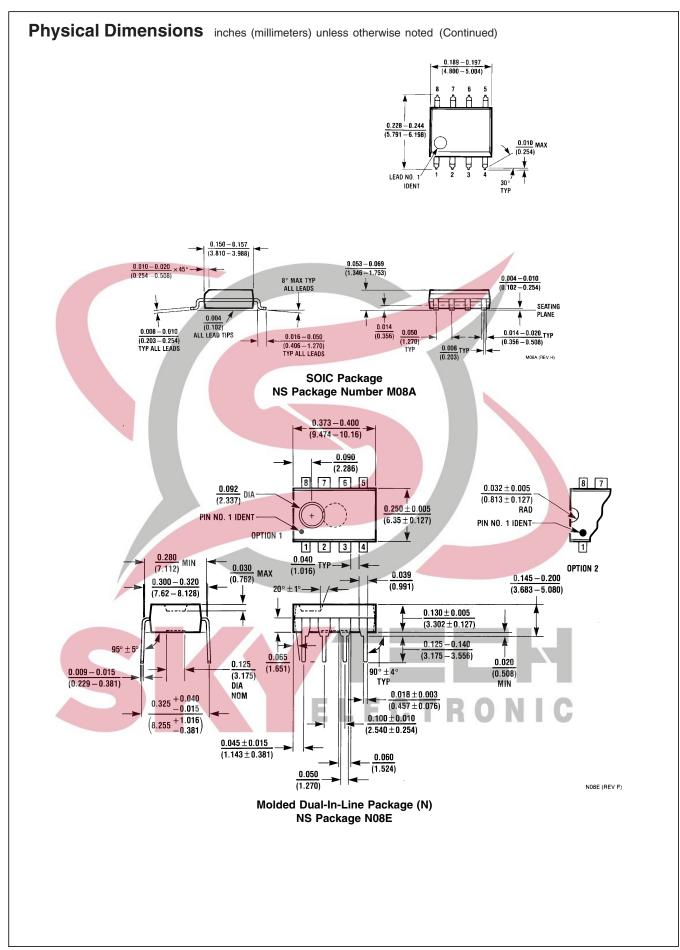


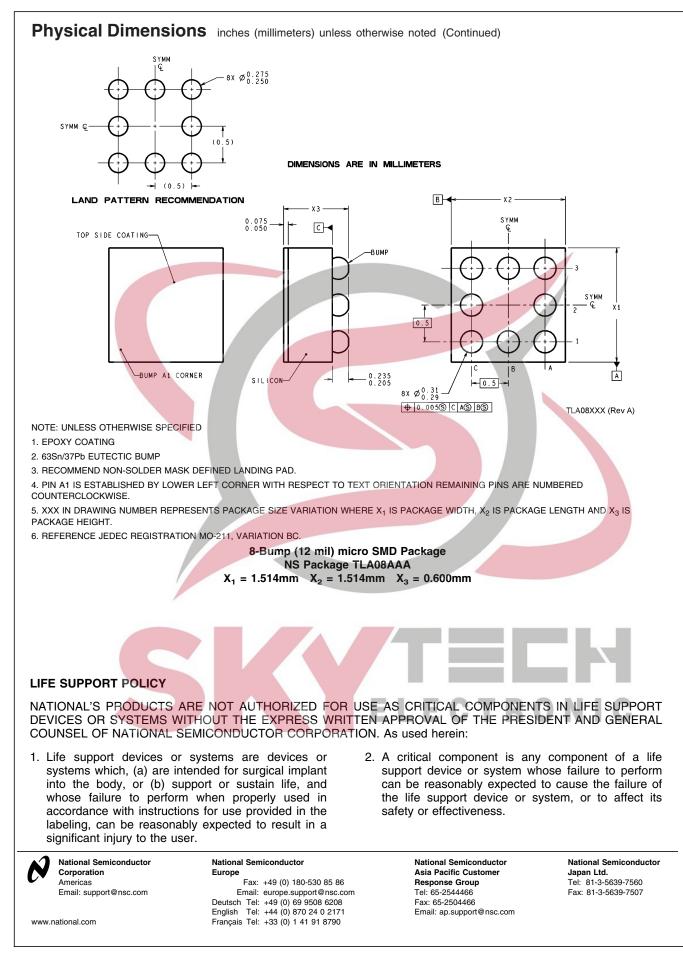






LM193/LM293/LM393/LM2903





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